





(MPM-90-xxST)



















■ Features

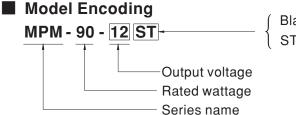
- 3.43"x2.05" compact size
- · PCB, chassis or screw terminal mounting version
- Medical safety approved (2 x MOPP) according to ANSI/AAMI ES60601-1 and IEC/EN60601-1
- · Suitable for BF application with appropriate system consideration
- No load power consumption<0.1W
- Extremely low leakage current
- Wide operating temp. range -30 ~ +80°C
- · EMI Class B without additional components
- Isolation Class $\scriptstyle II$
- Protections: Short circuit / Overload / Over voltage
- · No minimum load required
- Operating altitude up to 4000 meters (Note.7)
- 100W peak(10 sec.)
- · 3 years warranty

Applications

- · Portable medical device
- Mobile clinical workstation
- · Medical computer monitor
- · Medical examination instrument

Description

MPM-90 is a 90W high density and small size (87x52x29.5mm) AC/DC PCB-mount module type medical grade power supply . It features the operation for $80\sim264VAC$, a low no load power consumption less than 0.1W, a high efficiency up to 93%, Class II (no FG) double insulation, outstanding dissipation, $2\sim5G$ anti-vibration by model, high EMC performance, 4KVAC isolation, etc. The design observes IEC/EN60601-1 and ANSI/AAMI ES60601-1 version three with 2 x MOPP level and ultra-low leakage current (<100µA). It is very suitable for BF (patient contact) type medical device or relevant equipment.



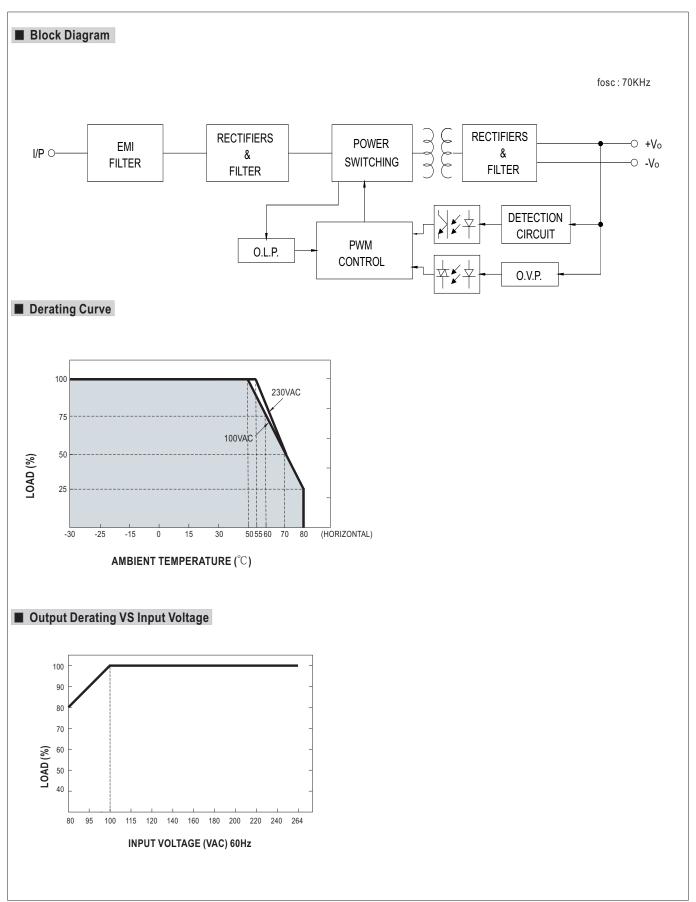
Blank: PCB mounting style
ST: Screw terminal style



SPECIFICATION

			MPM-90-12		MPM-90-15	MPM-90-2	4 🗌	MPM-90-48
	DC VOLTAC	GE	12V		15V	24V		48V
	Peak(10 sec.)		7.37A		6.23A	4.13A		2.07A
	CURRENT	Convection	6.7A		5.67A	3.75A		1.88A
	RATED	Peak(10 sec.)Note.2	88.4W		93.5W	99W		99.2W
	POWER	Convection	80.4W		85.05W	90W		90.2W
	RIPPLE & NOISE (max.) Note.3				150mVp-p	200mVp-p		240mVp-p
OUTPUT	VOLTAGE TOLERANCE Note.4				±2.0%	±2.0%		±2.0%
	LINE REGULATION		±0.5%			±0.5%		
			±1.0%		±0.5%			±0.5%
	LOAD REGULATION							
	SETUP, RISE TIME		1000ms, 30ms/230VAC 1000ms, 30ms/115VAC at full load					
	HOLD UP TIME (Typ.)		30ms/230VAC 10ms/115VAC at full load					
	VOLTAGE RANGE Note.5							
	FREQUENCY RANGE		47 ~ 63Hz					
INPUT	EFFICIENCY (Typ.)		92%		92.5%	93%		93%
INFUI	AC CURRENT (Typ.)		1.9A/115VAC 1.1A/230VAC					
	INRUSH CURRENT (Typ.)		COLD START 30A/115VAC 65A/230VAC					
	LEAKAGE CURRENT (max.) Note.6		Touch current <100 μA/264VAC					
	OVERLOAD OVER VOLTAGE OVER TEMPERATURE		115% ~ 160% rat	ted output c	oower			
			115% ~ 160% rated output power Protection type : Hiccup mode, recovers automatically after fault condition is removed					
PROTECTION			12.6 ~ 16.2V 15.8 ~ 20.3V 25.2 ~ 32.4V 50.4 ~ 64.8V					
PRUIECIIUN								
ENVIRONMENT			Protection type: Shut down o/p voltage, re-power on to recover					
	WORKING TEMP.		Protection type: Shut down o/p voltage, re-power on to recover					
			-30 ~ +80°C (Refer to "Derating Curve")					
	WORKING HUMIDITY		20 ~ 90% RH non-condensing					
	STORAGE TEMP.		-40 ~ +85°C					
	TEMP. COEFFICIENT		±0.03%/°C (0~50°C)					
	SOLDERING TEMPERATURE VIBRATION							
			Blank:10 ~ 500Hz, 2G 10min./1cycle, period for 60min. each along X, Y, Z axes					
			ST:10 ~ 500Hz, 5G 10min./1cycle, period for 60min. each along X, Y, Z axes					
	OPERATING ALTITUDE Note.7							
	SAFETY STANDARDS		IEC60601-1, EN60601-1, EAC TP TC 004, UL ANSI/AAMI ES60601-1(3.1 version), CAN/CSA-C22 3rd Edition approved; Design refer to EN60335-1(by request)					
		ANDANDO			hv renuest)			
	ISOLATION		Primary-Seconda					
	ISOLATION WITHSTAN	LEVEL D VOLTAGE	Primary-Seconda I/P-O/P:4KVAC	ary: 2xMOP	P			
	ISOLATION WITHSTAN	LEVEL	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Or	ary: 2xMOP	DC / 25°C / 70% RH	ard	Test Le	evel / Note
	ISOLATION WITHSTAN	LEVEL D VOLTAGE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter	ary: 2xMOP	DC / 25°C / 70% RH Stanc			evel / Note
	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted	ary: 2xMOP	DC / 25°C / 70% RH Stanc EN55	011 (CISPR11)	Class E	3
	ISOLATION WITHSTAN	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated	ary: 2xMOP	DC / 25°C / 70% RH Stanc EN55	011 (CISPR11) 011 (CISPR11)	Class E	3
	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre	ary: 2xMOP	DC / 25°C / 70% RH Stanc EN556 EN556 EN61	011 (CISPR11) 011 (CISPR11) 000-3-2	Class E	3
SAFETY &	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker	ary: 2xMOP	DC / 25°C / 70% RH Stanc EN556 EN556 EN61	011 (CISPR11) 011 (CISPR11)	Class E	3
EMC	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2	ary: 2xMOP	DC / 25°C / 70% RH Stanc EN550 EN550 EN61	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3	Class E Class E Class A	3 3 A
	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter	ary: 2xMOP	DC / 25°C / 70% RH Stance EN550 EN61 EN61 Stance Stanc	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3	Class E Class A Test Le	3 3 A evel / Note
EMC	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2	ary: 2xMOP	DC / 25°C / 70% RH Stance EN550 EN61 EN61 Stance Stanc	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3	Class E Class A Class A Test Le	B B Bevel / Note , 15KV air ; Level 4, 8KV contact
EMC	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter	nms / 500VI	DC / 25°C / 70% RH Stanc EN556 EN556 EN61 Stanc EN61	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3	Class E Class A Test Le Level 4 Level 3	B B B B B B B B B B B B B B B B B B B
EMC	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Or Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept	nms / 500VI	DC / 25°C / 70% RH Stance EN550 EN550 EN61 Stance EN61	011 (CISPR11) 0111 (CISPR11) 000-3-2 000-3-3 ard 000-4-2	Class E Class A Class B Class B Class B Class A Class B Class	evel / Note , 15KV air ; Level 4, 8KV contact i, 10V/m(80MHz~2.7GHz) , 9~28V/m(385MHz~5.78GHz)
EMC	ISOLATION WITHSTAN ISOLATION EMC EMISS	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Or Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts	nms / 500VI	DC / 25°C / 70% RH Stanc EN55 EN55 EN61 EN61 EN61 EN61	011 (CISPR11) 0111 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3	Class E Class A Test Le Level 4 Level 3 Table 9 Level 3	B B B B B B B B B B B B B B B B B B B
EMC	ISOLATION WITHSTAN ISOLATION	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts Surge susceptib	nms / 500VI	DC / 25°C / 70% RH	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3 000-4-4 000-4-5	Class E Class A Class B Class A Class B Class A Class B Class	B B B B B B B B B B B B B B B B B B B
EMC	ISOLATION WITHSTAN ISOLATION EMC EMISS	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Or Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts	nms / 500VI	DC / 25°C / 70% RH	011 (CISPR11) 0111 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3	Class E Class A Test Le Level 4 Level 3 Table 9 Level 3	B B B B B B B B B B B B B B B B B B B
EMC	ISOLATION WITHSTAN ISOLATION EMC EMISS	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts Surge susceptib	nms / 500VI	DC / 25°C / 70% RH Stanc EN55 EN55 EN61 EN61 Stanc EN61 EN61 EN61 EN61 EN61 EN61 EN61 EN61	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3 000-4-4 000-4-5	Class E Class A Class A Class A Class A Class A Class A Level 4 Level 3 Level 3 Level 3 Level 3	B B B B B B B B B B B B B B B B B B B
EMC	ISOLATION WITHSTAN ISOLATION EMC EMISS	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts Surge susceptib Conducted susce	nms / 500VI	Stance	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3 000-4-4 000-4-5 000-4-6	Class E Class A Class	Bevel / Note 1, 15KV air ; Level 4, 8KV contact 1, 10V/m(80MHz~2.7GHz) 1, 9~28V/m(385MHz~5.78GHz) 1, 2KV 1, 1KV/Line-Line 1, 10V 1, 30A/m dip 0.5 periods, 30% dip 25 periods
EMC	ISOLATION WITHSTAN ISOLATION EMC EMISS	LEVEL D VOLTAGE RESISTANCE	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts Surge susceptib Conducted susc Magnetic field in	ary: 2xMOP mms / 500VI nt ibility ieptibility munity erruption	Stance	011 (CISPR11) 0111 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3 000-4-4 000-4-5 000-4-6 000-4-8	Class E Class A Class A Class A Class A Class A Level 4 Level 3 Level 3 Level 3 Level 3 Level 4 >95% c >95% i	B B B B B B B B B B B B B B B B B B B
EMC Note 8)	ISOLATION WITHSTAN ISOLATION EMC EMISS	LEVEL D VOLTAGE RESISTANCE SION	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts Surge susceptib Conducted susc Magnetic field in Voltage dip, intee 570.5Khrs min.	ary: 2xMOP mms / 500VI nt ibility ibility peptibility munity erruption MIL-HDB	DC / 25°C / 70% RH Stanc EN55 EN55 EN61	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3 000-4-4 000-4-5 000-4-6 000-4-8 000-4-11 1514.81Khrs min.	Class E Class A Class A Class A Class A Level 4 Level 3 Level 3 Level 3 Level 4 >95% d >95% i	Bevel / Note , 15KV air ; Level 4, 8KV contact , 10V/m(80MHz~2.7GHz) , 9~28V/m(385MHz~5.78GHz) , 2KV , 1KV/Line-Line , 10V , 30A/m dip 0.5 periods, 30% dip 25 period nterruptions 250 periods R-332 (Bellcore) (25°C)
EMC	ISOLATION WITHSTAN ISOLATION EMC EMISS	LEVEL D VOLTAGE RESISTANCE SION	Primary-Seconda I/P-O/P:4KVAC I/P-O/P:100M Of Parameter Conducted Radiated Harmonic Curre Voltage Flicker EN60601-1-2 Parameter ESD RF field suscept EFT bursts Surge susceptib Conducted susc Magnetic field in Voltage dip, inte 570.5Khrs min. PCB mounting st	ary: 2xMOP mms / 500VI nt ibility ibility peptibility munity rruption MIL-HDB ryle : 87*52*	DC / 25°C / 70% RH Stanc EN556 EN556 EN61	011 (CISPR11) 011 (CISPR11) 000-3-2 000-3-3 ard 000-4-2 000-4-3 000-4-4 000-4-5 000-4-6 000-4-8	Class E Class A Class A Class A Level 4 Level 3 Level 3 Level 3 Level 4 >95% d >95% i Telcordia TR/Sf le: 109*52*33.5m	Bevel / Note , 15KV air ; Level 4, 8KV contact , 10V/m(80MHz~2.7GHz) , 9~28V/m(385MHz~5.78GHz) , 2KV , 1KV/Line-Line , 10V , 30A/m dip 0.5 periods, 30% dip 25 periods nterruptions 250 periods R-332 (Bellcore) (25°C) m (L*W*H)



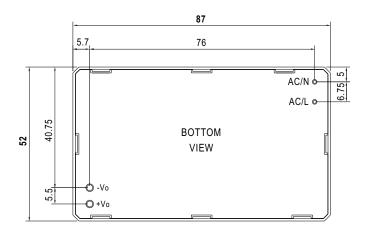


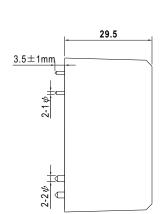
Case No.IRM60 Unit:mm



■ Mechanical Specification

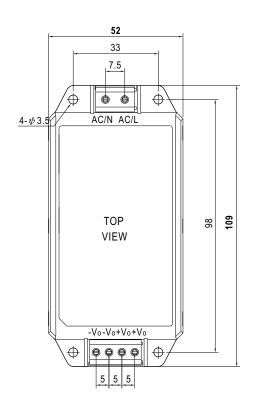
• PCB mounting style (MPM - 90)

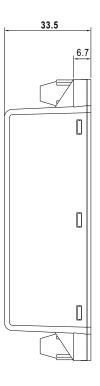




AC/L, AC/N P/N diameter:1 ψ +Vo, -Vo P/N diameter:2 ψ

• Screw terminal style (MPM-90-xxST)





■ Installation Manual

Please refer to : http://www.meanwell.com/manual.html